

Bipolar Transistor

(-)100 V, (-)2 A, Low V_{CE}(sat), (PNP)NPN Single TP/TP-FA

2SA1593 / 2SC4135

Features

- Adoption of FBET, MBIT Process
- Fast Switching Speed
- Small and Slim Package Permitting 2SA1593 / 2SC4135 Applied Sets to be Made More Compact
- High Breakdown Voltage and Large Current Capacity

Applications

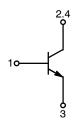
• Power Supplies, Relay Drivers, Lamp Drivers

SPECIFICATIONS (): 2SA1593 ABSOLUTE MAXIMUM RATINGS at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}	-	(-)120	V
Collector-to-Emitter Voltage	V _{CEO}	-	(-)100	V
Emitter-to-Base Voltage	V _{EBO}	-	(-)6.0	V
Collector Current	I _C	-	(-)2.0	Α
Collector Current (Pulse)	I _{CP}	-	(-)3.0	Α
Collector Dissipation	P _C	-	1.0	W
		T _C = 25°C	15	W
Junction Temperature	Tj	-	150	°C
Storage Temperature	T _{stg}	_	– 55 to +150	°C

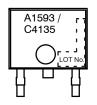
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CONNECTION





MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping [†]
2SA1593S-TL-E	DPAK / TP-FA	700 / Tape & Reel
2SC4135T-TL-E	DPAK / TP-FA	700 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (at Ta = 25°C)

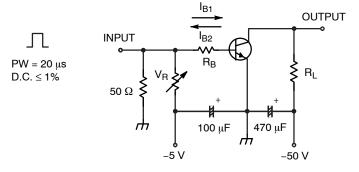
			Ratings			
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} = (-)100 V, I _E = 0 A	-	_	(-)100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} = (-)4 V, I _C = 0 A	-	-	(-)100	nA
DC Current Gain	h _{FE}	$V_{CE} = (-)5 \text{ V}, I_{C} = (-)100 \text{ mA}$	100*	-	400*	
Gain-Bandwidth Product	f _T	$V_{CE} = (-)10 \text{ V}, I_{C} = (-)100 \text{ mA}$	-	120	-	MHz
Output Capacitance	Cob	V _{CB} = (-)10 V, f = 1MHz	-	(25)16	-	pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C = (-)1 A, I _B = (-)100 mA	-	(-0.22)0.13	(-0.6)0.4	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C = (-)1 A, I _B = (-)100 mA	-	(-)0.85	(-)1.2	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C = (-)10 μA, I _E = 0 A	(-)120	-	-	V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I_C = 1 mA, R_{BE} = ∞	(-)100	-	-	V
Emittert-to-Base Breakdown Voltage	V _{(BR)EBO}	$I_E = 10 \mu A, I_C = 0 A$	(–)6	-	-	V
Turn-On Time	t _{on}	See specified Test Circuit	-	(80)80	-	ns
Storage Time	t _{stg}	1	-	(750)1000	-	ns
Fall Time	t _f	1	-	(40)50	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{*} The 2SA1593/ 2SC4135 are classified by 100 mA $h_{\mbox{\scriptsize FE}}$ as follows :

Rank	R	S	T
h _{FE}	100 to 200	140 to 280	200 to 400

Switching Time Test Circuit

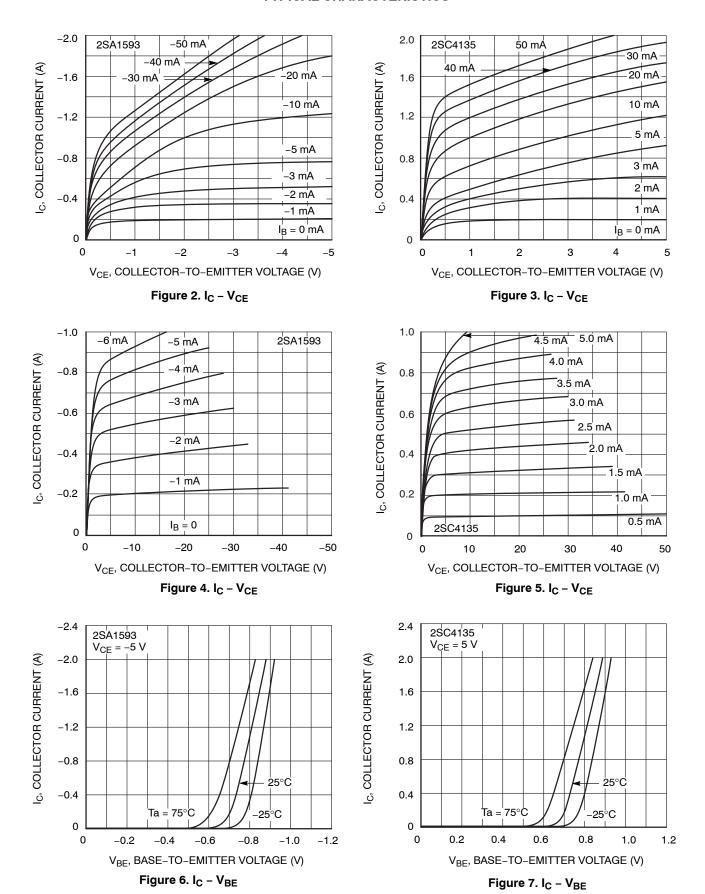


 $I_C = 10I_{B1} = -10I_{B2} = 0.7 \text{ A}$ (For PNP, the polarity is reversed)

Figure 1. Test Circuit

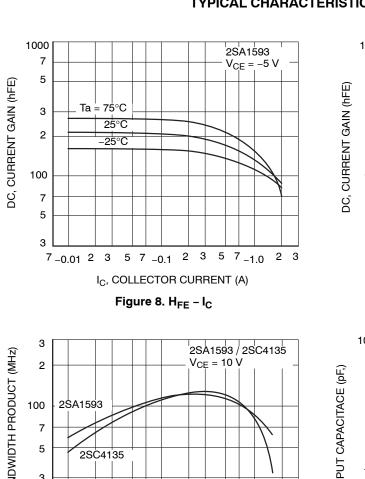
2SA1593 / 2SC4135

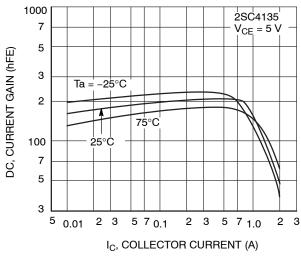
TYPICAL CHARACTERISTICS

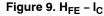


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TYPICAL CHARACTERISTICS (CONTINUED)







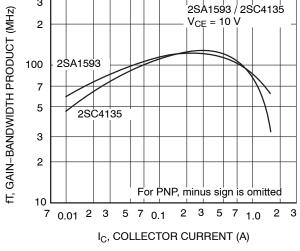


Figure 10. f_T - I_C

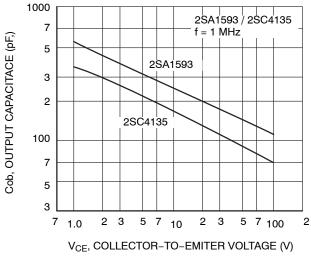


Figure 11. Cob - V_{CB}

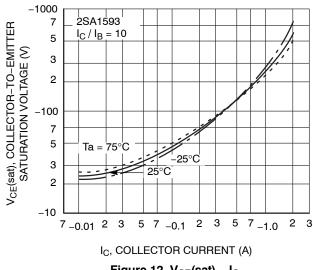


Figure 12. V_{CE}(sat) - I_C

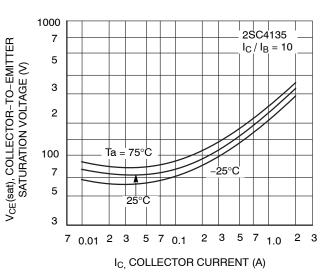


Figure 13. V_{CE}(sat) - I_C

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TYPICAL CHARACTERISTICS (CONTINUED)

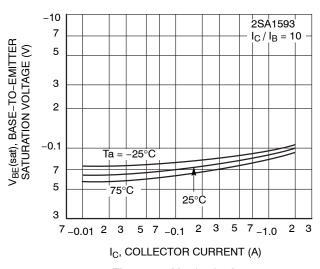


Figure 14. V_{BE}(sat) - I_C

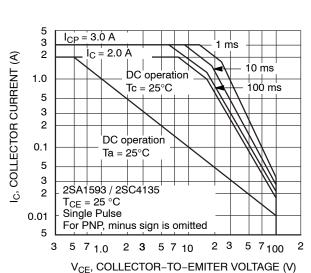


Figure 16. ASO

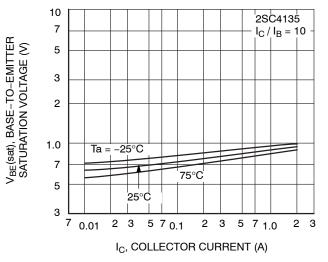


Figure 15. V_{BE}(sat) - I_C

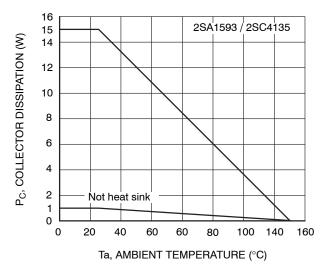
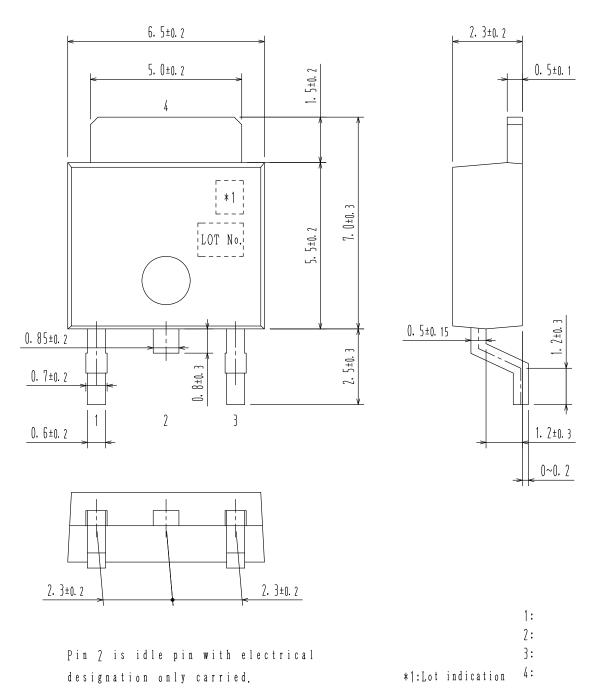


Figure 17. P_C -Ta

DPAK / TP-FA CASE 369AH ISSUE O

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